# NSN 5961-00-485-5166

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-00-485-5166

#### Inclosure Material:

Metal

**Overall Length:** 

0.460 inches

## Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.687 inches

#### Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 3 tab, solder lug

## Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

#### Fiig:

A110a0